

IPA057N08N3GXKSA1

IPA057N08N3GXKSA1 Information



Part Number	IPA057N08N3GXKSA1	
Manufacturer	Infineon Technologies	
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
Description	MOSFET N-CH 80V 60A TO220-3	
Package	TO-220-3 Full Pack	
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com	



Request a Quote

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPA057N08N3GXKSA1 Specifications

Manufacturer Part Number	IPA057N08N3GXKSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3 Full Pack
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	80V
Current - Continuous Drain (Id) @ 25°C	60A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	6V, 10V
Vgs(th) (Max) @ Id	3.5V @ 90µA
Gate Charge (Qg) (Max) @ Vgs	69nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4750pF @ 40V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	39W (Tc)
Rds On (Max) @ Id, Vgs	5.7 mOhm @ 60A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO220-FP
Package / Case	TO-220-3 Full Pack
	Report errors?

IPA057N08N3GXKSA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPA057N08N3GXKSA1 Payment Methods





If you have any question about IPA057N08N3GXKSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com